

**FOR IMMEDIATE RELEASE:  
Monday June 20, 2005**

**Quintessence Photonics Corporation wins development and production contract for high brightness semiconductor target designator laser**

(SYLMAR, CA) May 23, 2005 — Quintessence Photonics Corporation, a world leader in the design and manufacture of high brightness, high power semiconductor lasers, announced today that it has been awarded a product development contract and multi-year production contract for high brightness, direct diode, target designation lasers from one of the world's largest defense contractors. The defense customer completed a worldwide review of the available technology from traditional diode laser manufacturers and chose Quintessence based on its unique capability to produce high brightness semiconductor laser sources.

"We are thrilled to have the opportunity to provide this innovative high brightness semiconductor laser solution to our customer. We look forward to deploying this important defense product and to utilizing our proprietary BrightLase™ semiconductor laser technology to address many other defense and industrial applications" Paul Rudy, Vice President of Marketing and Sales at Quintessence, commented.

**About Quintessence Photonics Corporation**

Quintessence Photonics Corporation is a world leader in the development and commercialization of high brightness, high power semiconductor lasers for the industrial, defense, and medical markets. Founded in the year 2000, Quintessence is vertically integrated from epitaxy through packaging and performs all critical fabrication processes at its state-of-the-art high-technology facility in the Los Angeles suburb of Sylmar, CA. For more information, please visit [www.qpc.cc](http://www.qpc.cc) or contact George Lintz at (818) 833-4668 or by email at [info@qpc.cc](mailto:info@qpc.cc).